



041955 (153) HS-C²MOS™
041957 (253) INTEGRATED
CIRCUITS

PRELIMINARY DATA

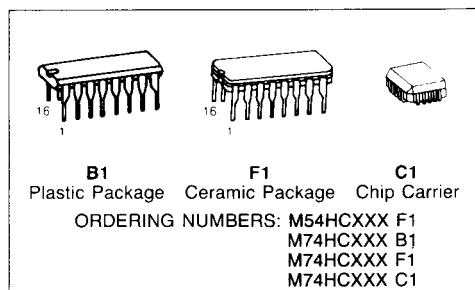
**HC153 DUAL 4-CHANNEL MULTIPLEXER
HC253 DUAL 4-CHANNEL MULTIPLEXER
3-STATE OUTPUT**

DESCRIPTION

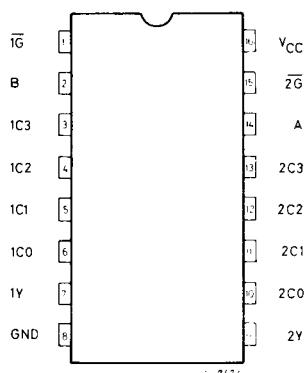
The M54/74HC153 and M54/74HC253 are high speed CMOS DUAL 4-CHANNEL MULTIPLEXERS fabricated with silicon gate C²MOS technology. Both achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation. The designer has a choice of complementary output (HC153) and 3-state output (HC253). Each of these data (1C0-1C3, 2C0-2C3) is selected by the two address input A and B. Separate strobe inputs ($1\bar{G}$, $2\bar{G}$) are provided for each of the two four-line sections. The strobe input (\bar{G}) can be used to inhibit the data output; the output of HC153 is fixed at a low level and the output of HC253 is disabled to be high impedance unconditionally, while the strobe input is held low. All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES

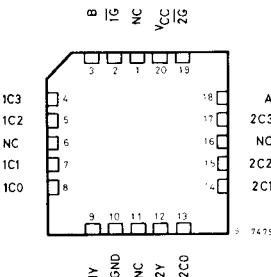
- High Speed
 $t_{PD} = 14 \text{ ns (Typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low Power Dissipation
 $I_{CC} = 4 \mu\text{A}$ (Max.) at $T_A = 25^\circ\text{C}$
- High Noise Immunity
 $V_{NIH} = V_{NIL} = 28\%$ V_{CC} (Min.)
- Output Drive Capability
10 LSTTL Loads
- Symmetrical Output Impedance
 $|I_{OH}| = I_{OL} = 4 \text{ mA (Min.)}$
- Balanced Propagation Delays
 $t_{PLH} = t_{PHL}$
- Wide Operating Voltage Range
 V_{CC} (opr) = 2V to 6V
- Pin and Function compatible with 54/74LS153/253



PIN CONNECTIONS
(top view)



Dual in line
CHIP CARRIER

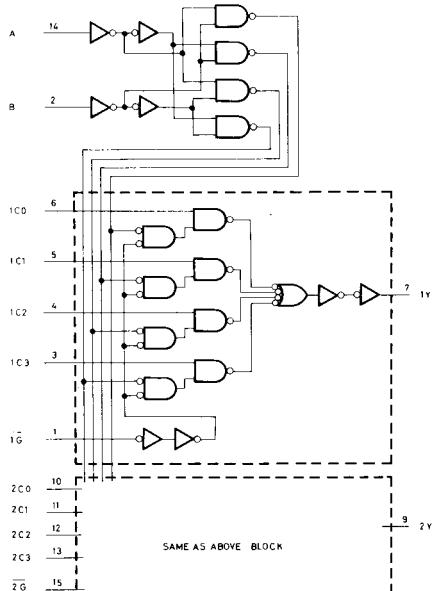


NC = No Internal Connection

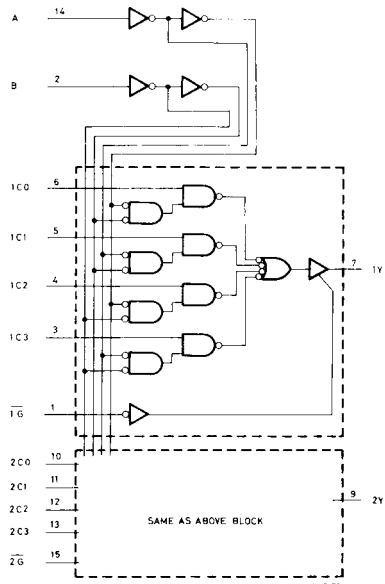


LOGIC DIAGRAM

HC153



HC253



TRUTH TABLE

SELECT INPUTS		DATA INPUTS				\bar{G}	OUTPUT Y	
B	A	C_0	C_1	C_2	C_3		HC153	HC253
*	*	*	*	*	*	H	L	Z
L	L	L	*	*	*	L	L	L
L	L	H	*	*	*	L	H	H
L	H	*	L	*	*	L	L	L
L	H	*	H	*	*	L	H	H
H	L	*	*	L	*	L	L	L
H	L	*	*	H	*	L	H	H
H	H	*	*	*	L	L	L	L
H	H	*	*	*	H	L	H	H

* Don't Care - Z: High Impedance



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	- 0.5 to 7	V
V_I	DC Input Voltage	- 0.5 to $V_{CC} + 0.5$	V
V_O	DC Output Voltage	- 0.5 to $V_{CC} + 0.5$	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Source Sink Current Per Output Pin	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 50	mA
P_D	Power Dissipation	500 (*)	mW
T_{STG}	Storage Temperature	- 65 to 150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

(*) 500 mW: $\leq 65^\circ\text{C}$ derate to 300 mW by 10 mW/°C: 65°C to 85°C .

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Limit	Unit
V_{CC}	Supply Voltage	2 to 6	V
V_I	Input Voltage	0 to V_{CC}	V
V_O	Output Voltage	0 to V_{CC}	V
T_A	Operating Temperature 74HC Series 54HC Series	- 40 to 85 - 55 to 125	°C
t_r, t_f	Input Rise and Fall Time	V_{CC} { 2 V 4.5V 6 V } 0 to 1000 ns 0 to 500 ns 0 to 400 ns	ns



DC SPECIFICATIONS

Symbol	Parameter	V _{CC}	Test Condition	T _A = 25°C 54HC and 74HC			- 40 to 85°C 74HC		- 55 to 125°C 54HC		Unit
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V _{IH}	High Level Input Voltage	2.0 4.5 6.0		1.5 3.15 4.2	— — —	— 3.15 4.2	1.5 3.15 4.2	— — —	1.5 3.15 4.2	— — —	V
V _{IL}	Low Level Input Voltage	2.0 4.5 6.0		— — —	— — —	0.5 1.35 1.8	— — —	0.5 1.35 1.8	0.5 1.35 1.8	— — —	V
V _{OH}	High Level Output Voltage	2.0 4.5 6.0 4.5 6.0	V _I V _{IH} or V _{IL}	I _O - 20 μA - 4.0 mA - 5.2 mA	1.9 4.4 5.9 4.18 5.68	2.0 4.5 6.0 4.31 5.8	— — — — —	1.9 4.4 5.9 4.13 5.63	— — — — —	1.9 4.4 5.9 4.10 5.60	V
V _{OL}	Low Level Output Voltage	2.0 4.5 6.0 4.5 6.0	V _{IH} or V _{IL}	20 μA 4.0 mA 5.2 mA	— — — — —	0 0 0.17 0.18	0.1 0.1 0.26 0.26	— — — —	0.1 0.1 0.33 0.33	0.1 0.1 0.40 0.40	V
I _I	Input Leakage Current	6.0	V _I = V _{CC} or GND	—	—	± 0.1	—	± 1	—	± 1	μA
I _{OZ}	3-State Output* Off-State Current	6.0	V _I = V _{IH} or V _{IL} V _O = V _{CC} or GND	—	—	± 0.5	—	± 5.0	—	± 10	μA
I _{CC}	Quiescent Supply Current	6.0	V _I = V _{CC} or GND I _O = 0	—	—	4	—	40	—	80	μA

*Note: Applied only for M54/74HC253

AC ELECTRICAL CHARACTERISTICS (V_{CC} = 5V, T_A = 25°C, Input t_r = t_f = 6ns)

Symbol	Parameter	CL (pF)	54HC and 74HC			Unit
			MIN.	TYP.	MAX.	
t _{TLH} t _{THL}	Output Transition Time	15		4	8	ns
t _{PLH} t _{PHL}	Propagation Delay Time (C _n - Y)	15		14	23	ns
t _{PLH} t _{PHL}	Propagation Delay Time (A, B - Y)	15		21	33	ns
t _{PZH} t _{PZL}	3-State Output Enable Time*	15		10	17	ns
t _{PHZ} t _{PLZ}	3-State Output Disable Time*	5		8	14	ns

* Only HC253

M54HC153/253**M74HC153/253****AC ELECTRICAL CHARACTERISTICS ($C_L = 50\text{pF}$, Input $t_r = t_f = 6\text{ns}$)**

Symbol	Parameter	V _{CC}	Test Condition	T _A = 25°C 54HC and 74HC			- 40 to 85°C 74HC		- 55 to 125°C 54HC		Unit
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t _{LH} t _{THL}	Output Transition Time	2.0 4.5 6.0		— — —	25 9 8	75 15 13	— — —	90 18 16	— — —	— — —	ns
t _{PLH} t _{PHL}	HC153/253 Propagation Delay Time (C _n - Y)	2.0 4.5 6.0		— — —	60 17 14	130 26 22	— — —	160 32 27	— — —	— — —	ns
t _{PLH} t _{PHL}	HC153/253 (A, B - Y)	2.0 4.5 6.0		— — —	92 25 21	195 39 33	— — —	235 47 40	— — —	— — —	ns
t _{PLH} t _{PHL}	HC153 Propagation Delay Time (Ḡ - Y)	2.0 4.5 6.0		— — —	92 25 21	195 39 33	— — —	235 47 40	— — —	— — —	ns
t _{PZL} t _{PZH}	HC253 Output Enable Time	2.0 4.5 6.0		— — —	40 12 10	100 20 17	— — —	120 24 21	— — —	— — —	ns
t _{PLZ} t _{PHZ}	HC253 Output Disable Time	2.0 4.5 6.0		— — —	25 14 13	115 23 22	— — —	140 28 26	— — —	— — —	ns
C _{IN}	Input Capacitance			—	5	10	—	10	— — —	— — —	
C _{OUT}	Output Capacitance		HC253	—	7	—	—	—	— — —	— — —	
C _{PD} (*)	Power Dissipation		HC123	—	56	—	—	—	— — —	— — —	
			HC253	—	56	—	—	—	— — —	— — —	

Note (*) C_{PD} is defined as the value the IC's of internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the following equation hereunder.

$$I_{CC(\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per Channel).}$$